

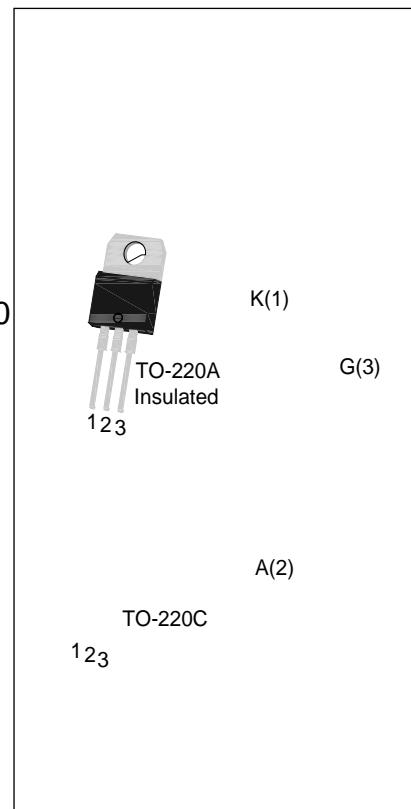


## JCT620X-FO Series 20A SCR

Rev.1.1

## DESCRIPTION:

With high ability to withstand the shock loading of large current, JCT620X-FO SCRs provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three terminals to external heatsink, JCT620A-FO provides a rated insulation voltage of 2500 V<sub>RMS</sub>, complying with UL standards (File ref: E252906). All the packages mentioned are RoHS compliant. (2011/65/EU)



## MAIN FEATURES

Symbol	JCT620
V <sub>DRM</sub> / V <sub>RRM</sub>	600V
I <sub>T(RMS)</sub>	20A
I <sub>GT</sub>	3~8mA

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40-150	
Operating junction temperature range	T <sub>j</sub>	-40-150	
Repetitive peak off-state voltage(T <sub>j</sub> =150 )	V <sub>DRM</sub>	600	V
Repetitive peak reverse voltage(T <sub>j</sub> =150 )	V <sub>RRM</sub>	600	V
RMS on-state current	TO-220A(Ins) (T <sub>c</sub> =100 ) TO-220C (T <sub>c</sub> =125 )	I <sub>T(RMS)</sub> 20	A
Average on-state current	TO-220A(Ins) (T <sub>c</sub> =100 ) TO-220C (T <sub>c</sub> =125 )	I <sub>T(AV)</sub> 13	A
Non repetitive surge peak on-state current (tp=10ms)	I <sub>TSM</sub>	250	A
I <sup>2</sup> t value for fusing (tp=10ms)	I <sup>2</sup> t	312.5	A <sup>2</sup> s

Critical rate of rise of on-state current ( $I_G=2 I_{GT}$ )	$dI/dt$	125	A s
Peak gate current	$I_{GM}$	4	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W

ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ C$  unless otherwise specified)

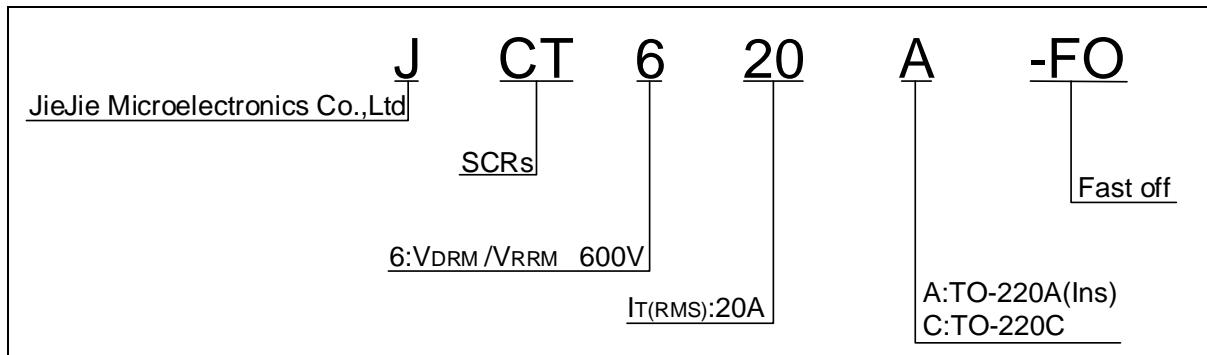
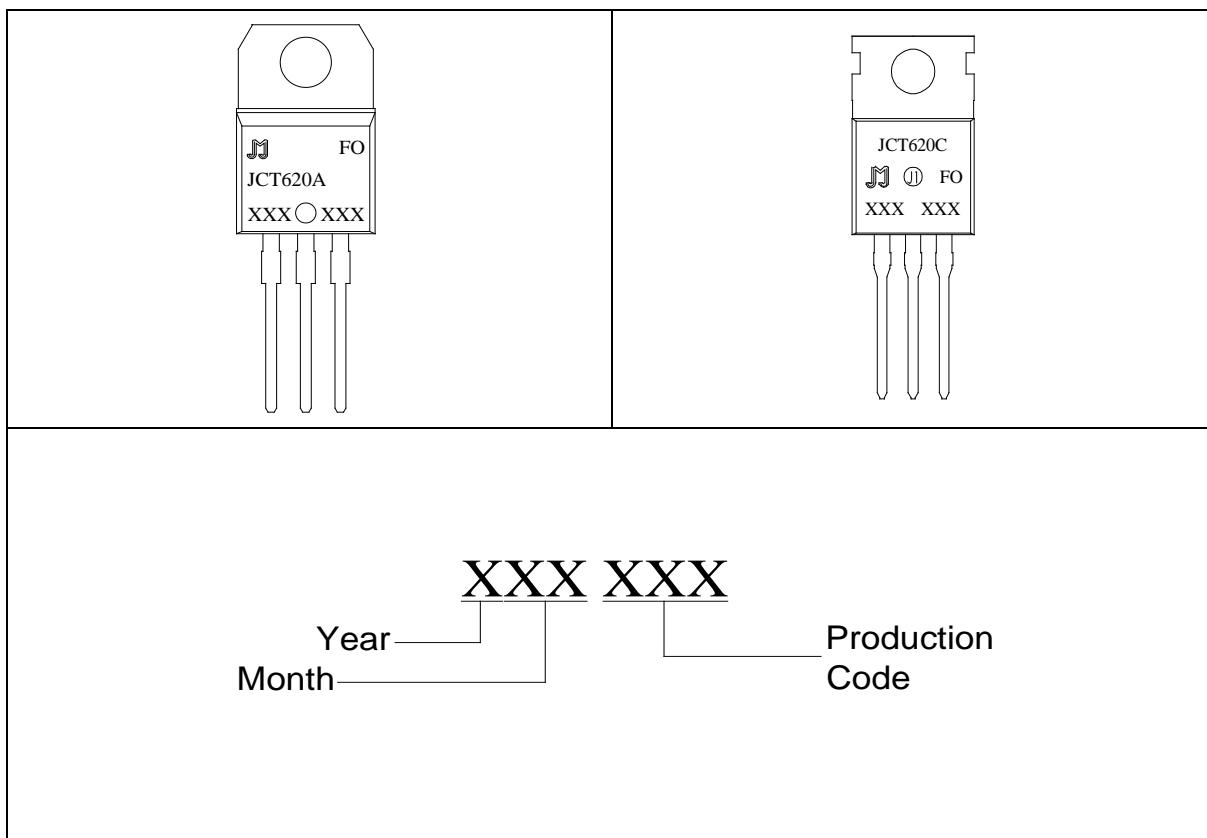
Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12V R_L=33$	3	-	8	mA
$V_{GT}$		-	-	1.3	V
$V_{GD}$	$V_D=V_{DRM} T_j=150^\circ C R_L=3.3K$	0.2	-	-	V
$I_L$	$I_G=1.2I_{GT}$	-	-	70	mA
$I_H$	$I_T=500mA$	-	-	60	mA
$dv/dt$	$V_D=2/3V_{DRM}$ Gate Open $T_j=150^\circ C$	300	-	-	V s
$t_{on}$	$I_G=20mA I_A=200mA I_R=20mA$ $T_j=25^\circ C$	-	-	4	s
$t_{off}$		-	-	12	s

## STATIC CHARACTERISTICS

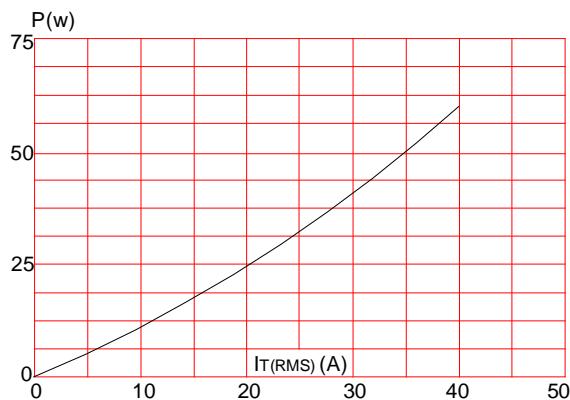
Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=40A$	$t_p=380\text{ s}$	$T_j=25^\circ C$	1.5 V
$V_{TO}$	Threshold voltage		$T_j=150^\circ C$	0.89 V
$R_d$	Dynamic resistance		$T_j=150^\circ C$	13.79 m
$I_{DRM}/I_{RRM}$	$V_D=V_{DRM}$	$V_R=V_{RRM}$	$T_j=25^\circ C$	5 A
			$T_j=150^\circ C$	1 mA

## THERMAL RESISTANCES

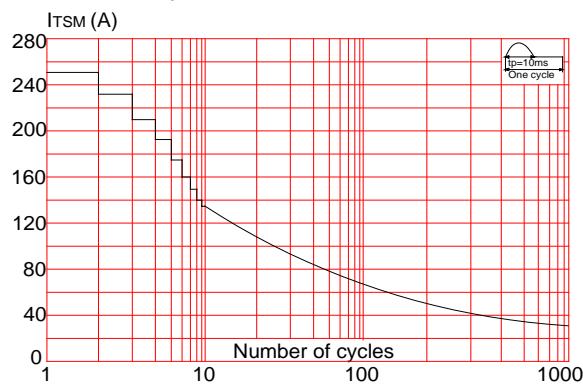
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-220A(Ins)	2	/W
		TO-220C	1	

**ORDERING INFORMATION****MARKING**

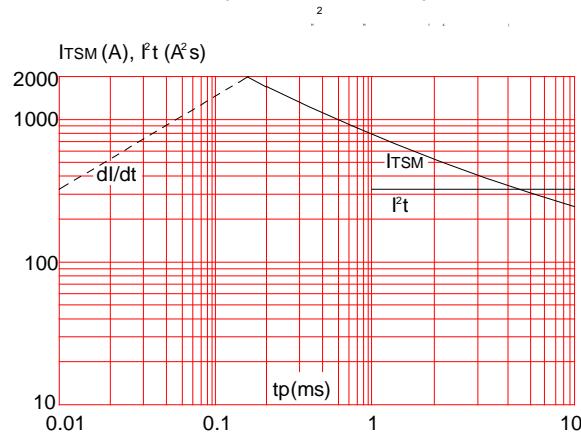
**FIG.1:** Maximum power dissipation versus RMS on-state current



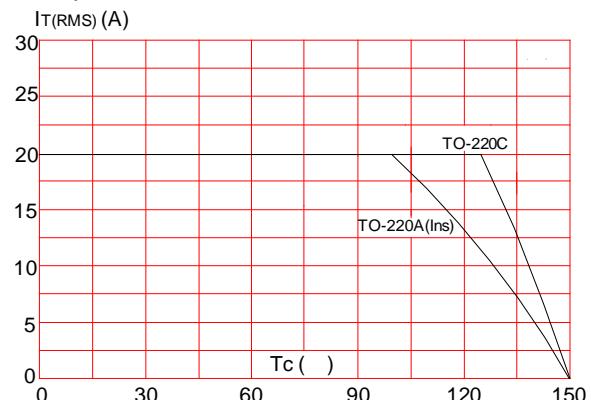
**FIG.3:** Surge peak on-state current versus number of cycles



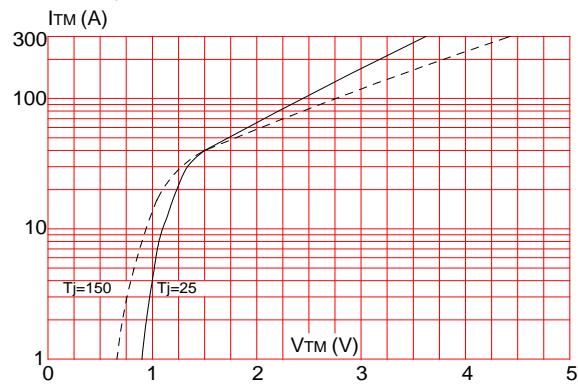
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 10\text{ms}$ , and



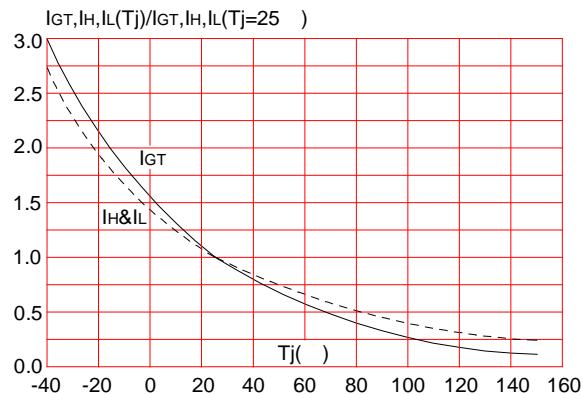
**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



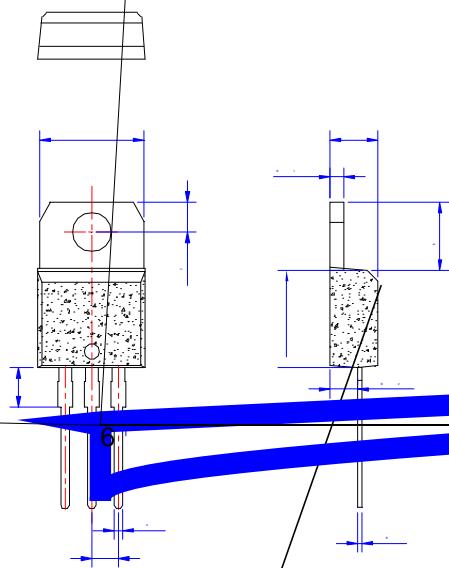
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT620A-FO	600	3~8	TO-220A(Ins)	50	Tube
JCT620C-FO			TO-220C		

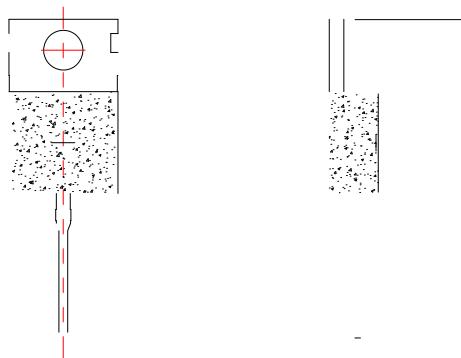
**Document Revision History**

Date	Revision	Changes
Jun 21, 2022	1	Last update
Sept 5, 2022	1.1	Add $I_{T(AV)}$

**PACKAGE MECHANICAL DATA**



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